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ABSTRACT

Variable filters, which central wavelength of the bandpass shifts along one dimension of the component, is a promising way to simplify and to miniaturize imaging spectrophotometer systems for spatial observation. In fact, by combining a dispersive element and a variable filter, it is possible to realize a spectral and a spatial filtering based on pushbroom technique. While there were numerous methods developed in order to produce variable filters, at this date, there is no simple, reliable and repeatable method. In this paper, we present a new method for the fabrication of variable filters based on plasma assisted reactive magnetron sputtering (PARMS).

Variable filters are obtained upon the variation of the thickness of some or all the layers deposited on the substrate. The layers are deposited using a Bühler HELIOS machine in order to benefit from the high stability of the deposition process. To insure a non-uniformity of the deposited layers, adapted masks are placed in front of the targets for the low and high refractive index materials. The uniformity of these layers is measured via a custom set-up allowing a local measurement of the transmission to perform a mapping of the transmission over the whole component aperture.

In this paper, we present the fabrication of layers and filters with variable thickness. Various types of thickness gradients are presented.

Keywords: Optical interferential filter, magnetron sputtering, variable filter

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1. INTRODUCTION

Variable filters, which central wavelength of the bandpass shifts along one dimension of the component, is a promising way to simplify and to miniaturize imaging spectrophotometer systems for spatial observation. In fact, by combining a dispersive element and a variable filter, it is possible to realize a spectral and a spatial filtering based on pushbroom technique [1]. While there were numerous methods developed in order to produce variable filters, at this date, there is no simple, reliable and repeatable method. In this paper, we present a new method for the fabrication of variable filters based on plasma assisted reactive magnetron sputtering (PARMS).

Variable filters are obtained upon the variation of the thickness of some or all the layers deposited on the substrate. The layers are deposited using a Bühler HELIOS machine [2] in order to benefit from the high stability of the deposition process. To insure a non-uniformity of the deposited layers, adapted masks are placed in front of the targets for the low and high refractive index materials. The uniformity of these layers is measured via a custom set-up allowing a local measurement of the transmission to perform a mapping of the transmission over the whole component aperture [3].

We first present the results obtained for single layers of high and low refractive index materials, respectively Nb$_2$O$_3$ and SiO$_2$. The results are used to validate the shape of the mask and to confirm the evolution of the thickness as a function of the position on the substrate.

We then demonstrate the fabrication of a narrow bandpass variable filter where the thicknesses of all the layers are changing, resulting in an overall shift of the filter.
2. EXPERIMENTAL SET UP TO CREATE A GRADIENT

2.1 Deposition system

The deposition technology used in this work is plasma assisted reactive magnetron sputtering (PARMS) with a HELIOS machine from Bühler Optics. This set up, installed in the Espace Photonique of the Institut Fresnel, is constituted of:

- 12 positions for substrate up to 100 mm diameter with one position dedicated to optical monitoring,
- a rotating plate at 240 rounds per minute,
- a load lock,
- 4 processing zones (2 MF sputtering sources for dielectric material, 1 DC sputtering source for metals and 1 assistance plasma),
- a in-situ optical monitoring in transmission,
- available target: Si, Nb, Hf, Ta, Ag, Cr and Al,
- available gas: Ar, O₂ and N₂.

The HELIOS machine has been shown to be a very reliable machine for the deposition of very complex filters composed with up to several hundreds of layers. In particular, we have demonstrated complex bandpass filers within the framework of various space projects, e.g. IDEFIX, TARANIS or 3MI [4-6]. For these projects, deposition of multilayer stacks composed with more than one hundred layers with total thickness up to 25 µm were needed and filters with spectral performances which do not deviate from theory by more than a few percent over broad spectral ranges were demonstrated. Within this project, we aim at fabricating a very narrowband filters with broad rejection for visible region. Preliminary designs have shown that ~130-layer stacks would be required for a total thickness ~18 µm. The HELIOS machine, compared to classical plasma assisted evaporation set up, appears as highly appropriate for this application.

The work presented in this paper is the result of a close collaboration with Bühler Optics in Alzenau that aims at developing an adapted masking technology to generate a controlled thickness variation along one direction on the substrate.

2.2 Masking technology

The masking technology, developed for this application, relies on the control of the deposition time using the geometry of the deposition chamber. First, it is important to note that the deposition of material on a given substrate is intermittent since the substrate is on a rotating plate. The targets being fixed and positioned within a few millimeters from the substrates, the deposition occurs only when the substrate is under the targets, i.e. over an approximately 120 × 120 mm² zone. The deposited thickness is then proportional to the time during which the substrate is in front of the targets (i.e. the speed of rotation of the substrate holder) and the deposition rate of the material (function of the sputtering parameters). In nominal configuration, uniformity masks are placed between the turntable and the targets. These masks are commonly used to guarantee a very good uniformity of the deposited layers. The idea developed for this project consisted in generating new masks that will produce an opposite effect to those generally used and thus generate a thickness gradient.

The developed technique consists in keeping uniformity masks below the target which guarantee a uniform distribution of sputtered material and to add new masks directly on the shutter to control the deposition time of material along the radial direction on the substrate.

This type of shutter and mask were designed, made and then installed on the HELIOS machine of the Fresnel Institute, in collaboration with Bühler company. The control programs of the machine have also been adapted to allow the use of the mask.

Figure 1 shows a picture of the masking system, when the machine is open. When the machine is closed, the cover is positioned in front of the substrate holder and the shutter is then located a few millimeters from the substrate holder. In the left picture, the shutter is closed. This position makes it possible to completely hide the targets and thus to achieve target conditioning before the deposition. In the right picture, the same shutter is turned by 15° in the so-called open position. The layers are deposited through this mask and thus it is possible to control the deposition time radially.
2.3 Principle of the generation of a variable filter

In order to validate the principle of a gradient generation, we designed a first mask, as illustrated in the Figure 2. It has 3 zones:

- A uniform 35 mm area to perform in-situ optical monitoring. This area allows to control the thickness deposited in the region having the thinnest material thickness.
- An area whose aperture varies by a factor of 3 over a distance of 10 mm. It is this area that will be used to generate a thickness gradient with a ratio close to or equal to 3.
- Another uniform area in which aperture equal to 10 mm. This area avoids the shading effects associated with the edge of the mask.
the Espace Photonique platform [3]. Figure 3 illustrates the evolution of the transmission due to the thickness gradient thus
created along the x direction.

We can then identify different zones:

- Between 0 and 5 mm, the targets are completely masked and there is no deposition. The transmission is that of a bare substrate.
- Between 5 and 10 mm, this is the beginning of the 35 mm uniform area. A shadowing effect due to the edge of the mask are visible inducing the generation of a thickness gradient. This results in a redshift of the central wavelength of the filter.
- Between 10 and 40 mm, this is the uniform zone of the 35 mm area. We observe a quasi-uniform zone with a filter centered at 450 nm.
- Between 40 and 55 mm, this is the area generating the gradient. We observe a shift of the central wavelength of the filter by a factor close to 3 allowing to shift from 450 to 1200 nm.
- Between 55 and 60 mm, there is a fairly uniform area corresponding to a central wavelength of the filter equal to 1200 nm.
- Between 60 and 65 mm, we observe the same effect as between 5 and 10 mm due to the edge of the mask. This produces a thickness gradient that results in a blue shift of the central wavelength of the filter.
- Between 65 and 70 mm, the targets are completely masked again and there is no deposition. The transmission is that of a bare substrate.

Figure 3 validates the feasibility of a linear gradient filter with this method. The variation of the central wavelength is close to 3 over a distance of 10 mm. It should therefore be noted that the deposition rate, with this mask, is reduced by a factor between 3 and 4 for the thickest zone. This means that the 18 μm final filter that we aim would require a deposition time greater than 50 hours. However, this method allows further increase of the aperture of the gradient masks that would allow depositing at rates no lower than half of regular deposition rates. Moreover, as seen on the right part in Figure 3, according to the method used to generate the gradient, a curvature of the iso-thickness lines will occur. The expected “smile” should be around 15 μm over a 5 mm filter width and should reach 50 μm over a 10 mm filter width. This value will be characterized later but should not be a problem since the filter is used in front of a camera that will numerically correct this defect.
3. DEPOSITION OF SINGLE LAYER WITH VARIABLE THICKNESS

In order to precisely characterize the generated gradients, we have carried out the deposition of two simple structures:

- a single layer of Nb$_2$O$_5$ deposited through an adapted mask (see 2.3 part) on a silica substrate,
- a single layer of SiO$_2$ deposited through the same mask on a silica substrate previously coated with a uniform Nb$_2$O$_5$ layer.

The mask, used to perform the gradient, has a structure very similar to that shown in Figure 2. Contrary to the mask presented in the above section, an unmasked area of 5 mm appears between the uniform and the gradient zones. The shape ratio between the thinner and the thicker part is of 2. The local transmission is measured with the uniformity measuring bench and then, by reverse engineering, the local thickness of the deposited layer is calculated (Figure 4).

We can see on each graph in Figure 4 that 2 zones are present:

- an area between 9 and 19 mm with a thickness variation by a factor close to 2 (165 to 300 nm),
- a uniform zone between 30 and 45 mm with a thickness equal to 165 nm.

It can also be noted that the gradient is almost linear, and that the gradients generated by the Nb$_2$O$_5$ or SiO$_2$ targets are very close, which should make it possible the production of high performance variable filters.

![Figure 4. Gradient characterization for single layers of SiO$_2$ and Nb$_2$O$_5$.](image)

4. DEPOSITION OF A NARROW BANDPASS FILTER WITH VARIABLE THICKNESS

In order to experimentally validate our ability to achieve a narrow bandpass filter similar to that required for this project, we have tested the fabrication of a very narrow bandpass filter (without blocking filters) composed of a double Fabry-Perot cavity with 23 layers with the following structure:

\[
[(H L)^2 H 2L H (L H)^2] L [(H L)^2 H 2L H (L H)^2]
\]

where H and L are quarter-wave optical thickness layers at a 450 nm wavelength respectively made of Nb$_2$O$_5$ and SiO$_2$. The filter was deposited using the HELIOS machine with the uniformity masks of Figure 2 positioned below each target. The evolution of the spectral response of the filter along the x direction (as shown in Figure 3) has been measured with the uniformity bench and is represented in Figure 5. Figure 6 illustrates the experimental and theoretical transmission for 2 different x positions.

Figures 5 and 6 validate the fact that we have been able to produce a very narrow band linearly variable filter with performances close to theoretical performance. This shows that, provided that blocking filters are added, this masking method appears as an appropriate method to produce linearly and non-linearly variable filters.
Figure 5. Evolution of the transmission of the narrow bandpass filter (on the left) and of the theoretical and experimental centering wavelength of the same filter (on the right).

Figure 6. Evolution of the theoretical (blue) and experimental (red) transmission of the narrow bandpass filter for two different $x$ positions.

5. CONCLUSION

We have demonstrated in this paper an efficient method for the generation of variable thickness filters and compatible with a Bühler HELIOS deposition machine and allowing the fabrication of complex filters. This method relies on the use of two uniformity masks, one for each material, fixed on the shutter. We have then demonstrated that this method could be used for the fabrication of narrowband filters and a first experimental demonstration was presented.

REFERENCES
